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PATENT & TRADEMARK OFFICE

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Hiroyuki Okuyama et al.
Appl. No.: 10/062,687
Filed: January 30, 2002
Title: SEMICONDUCTOR LIGHT-EMITTING DEVICE AND PROCESS FOR
PRODUCING THE SAME
Art Unit: Unknown
Examiner: Unknown
Docket No.: 1123278-005

Assistant Commissioner for Patents
Washington, DC 20231

INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 37 C.F.R. 1.97, and 37 C.F.R. 1.98, Applicants request that a citation and examination of the references cited below, and on the attached PTO-1449 form, copies of which are enclosed, be made during the course of examination of the above-identified application for United States patent.

FOREIGN PATENT DOCUMENTS

<u>Document No.</u>	<u>Date</u>	<u>Country</u>
6-45648	Feb. 18, 1994	Japan
9-129974	May 16, 1997	Japan
11-26883	1-29-99	Japan

OTHER DOCUMENTS

Applied Physics Letters, Vol. 76, Number 22, 29 May 2000, "Selective growth of InGaN quantum dot structures and their microphotoluminescence at room temperature, Tachibani et al, pages 3212-3214

Journal of Crystal Growth 189/190 (1998) 83-86, "Spatial control of InGaN luminescence by MOCVD selective epitaxy", Kaplnek et al.

Journal of Crystal Growth, Volume 204, No. 3, pp. 247-418 July 11 (1999), Stringfellow et al..

Applicants look forward to early and favorable consideration of this matter.

Respectfully submitted,

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